



# **DMN2114SN**

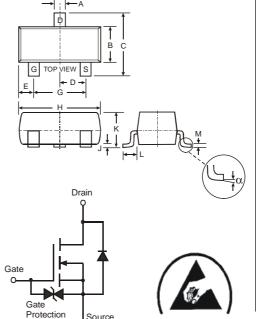
### N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

### **Features**

- Low On-Resistance
- Ideal for Notebook Computer, Portable Phone, PCMCIA Cards, and Battery Power Circuits
- Lead Free By Design/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- **ESD Protected Gate**
- "Green" Device (Note 3)

### **Mechanical Data**

- Case: SC-59
- Case Material Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.008 grams (approximate)



**ESD** protected

SC-59									
Dim	Min	Max							
Α	0.30	0.50							
В	1.40	1.80							
С	2.50	3.00							
D	0.85	1.05							
E	0.30	0.70 2.10 3.10 0.10							
G	1.70								
Н	2.70								
J	_								
K	1.00	1.40							
L	0.55	0.70							
М	0.10	0.35							
α	0°	8°							
All Dimensions in mm									

# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		V <sub>DSS</sub>	20	V		
Gate-Source Voltage	Continuous	V <sub>GSS</sub>	±12	V		
Drain Current	Continuous Pulsed	I <sub>D</sub>	1.2 4.0	А		
Total Power Dissipation		P <sub>d</sub>	500	mW		
Thermal Resistance, Junction to Ambient		$R_{ hetaJA}$	250	°C /W		
Operating and Storage Temperature Range		T <sub>i</sub> , T <sub>STG</sub>	-55 to +150	°C		

Diode

**EQUIVALENT CIRCUIT** 

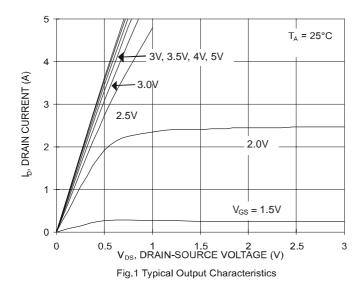
Notes:

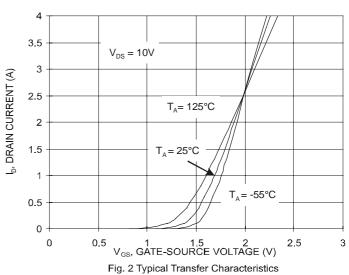
- Pulse width ≤300μS, duty cycle ≤2%.
- No purposefully added lead.
- Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.



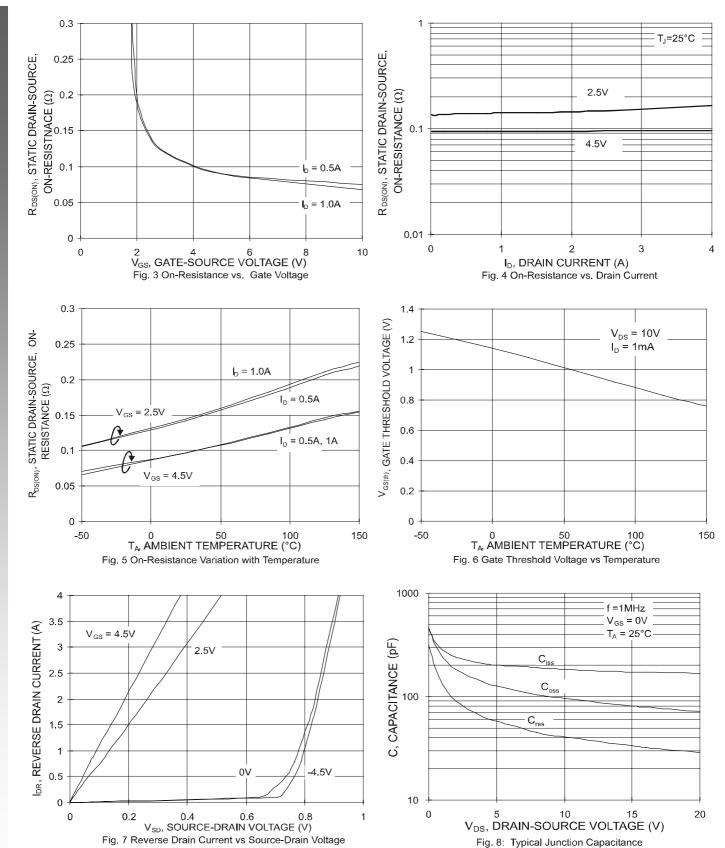
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 1)									
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$			
Zero Gate Voltage Drain Current	@ T <sub>j</sub> = 25°C	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 24V, V_{GS} = 0V$		
Gate-Body Leakage		I <sub>GSS</sub>	_	_	±10	μА	$V_{GS} = \pm 12V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 1)		_		÷.					
Gate Threshold Voltage		V <sub>GS(th)</sub>	0.7	_	1.40	V	$V_{DS} = 10V, I_D = 1.0mA$		
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	<u> </u>	0.100 0.160	Ω	$V_{GS} = 4.5V, I_D = 0.5A$ $V_{GS} = 2.5V, I_D = 0.5A$			
Forward Transfer Admittance		Y <sub>fs</sub>	_	3.3	_	S	$V_{DS} = 10V, I_D = 0.5A$		
Diode Forward Voltage		$V_{SD}$	_	0.8	1.1	V	$V_{GS} = 0V, I_S = 1.0A$		
DYNAMIC CHARACTERISTICS			-		-				
Input Capacitance			_	180	_	pF			
Output Capacitance		Coss	_	120	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	45	_	pF	1			
SWITCHING CHARACTERISTICS									
Turn-On Delay Time		t <sub>D(ON)</sub>		10		ns			
urn-Off Delay Time		t <sub>D(OFF)</sub>	_	50	_	ns	$V_{DD} = 10V, I_D = 0.5A,$		
Turn-On Rise Time				15	_	ns	$V_{GS} = 5.0V, R_{GEN} = 50\Omega$		
Turn-Off Fall Time	,	t <sub>f</sub>	_	45	_	ns			









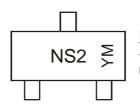


### Ordering Information (Note 4)

Device	Packaging	Shipping				
DMN2114SN-7	SC-59	3000/Tape & Reel				

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



NS2 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year		200	b	2007		2008	20	109	2010		2011		2012	
	Code	Т		U		V		W			Υ		Z	
	Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec	
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